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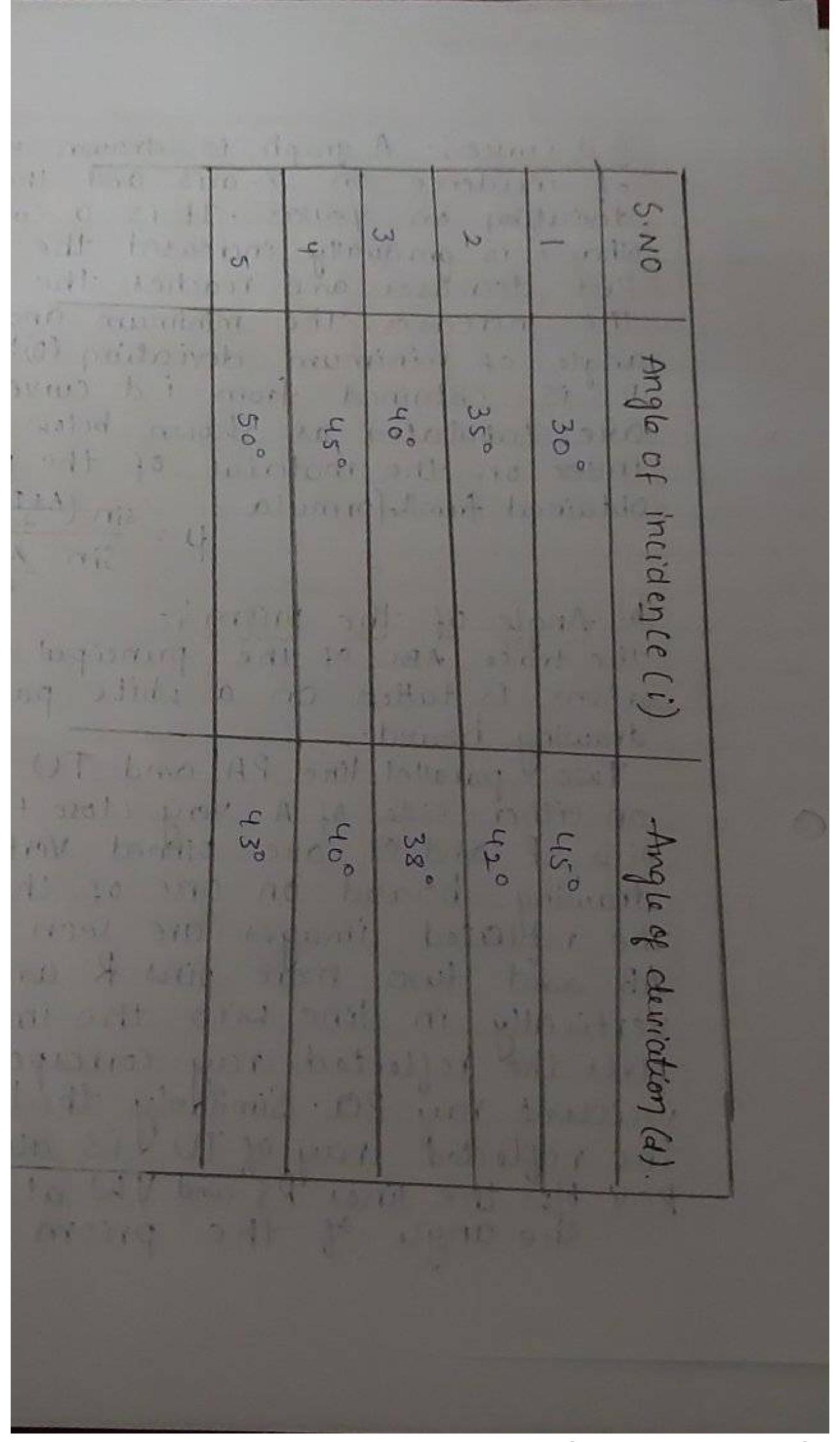
Procedure: To measure the angle of minimum deviation A White paper is fixed on a drawing board with the help of drawing pins the prism is placed on the white paper and its outline ABC! is drawn with sharp pencil. The prism is removed and normal is drawn at a point M on the refracting Surface AB. A Straight line is drawn at 'N' making an angle say 30 with the Normal Two points Panda are fisced Vertically on this line 2 cm apart. This is called incident ray The prism is placed in its positions the two points are viewed from the other refracting face Ac. Viewing the two pins, two more pins Rand S are fixed so that the Pins Rands are in the line with the images of Pand Q. The R and s are noted on the paper The prism is removed and points Rand S are joined with a Straight line. This is called emergent ray. It is extended to meet the incident at 'o'! The angle blw the incident ray and the emergent ray is called the angle deviation. The experiment is repeated for different angle of incidences 35°, 40°, 45°, 50, 55°. Every-lime, the angle of deviation measured.

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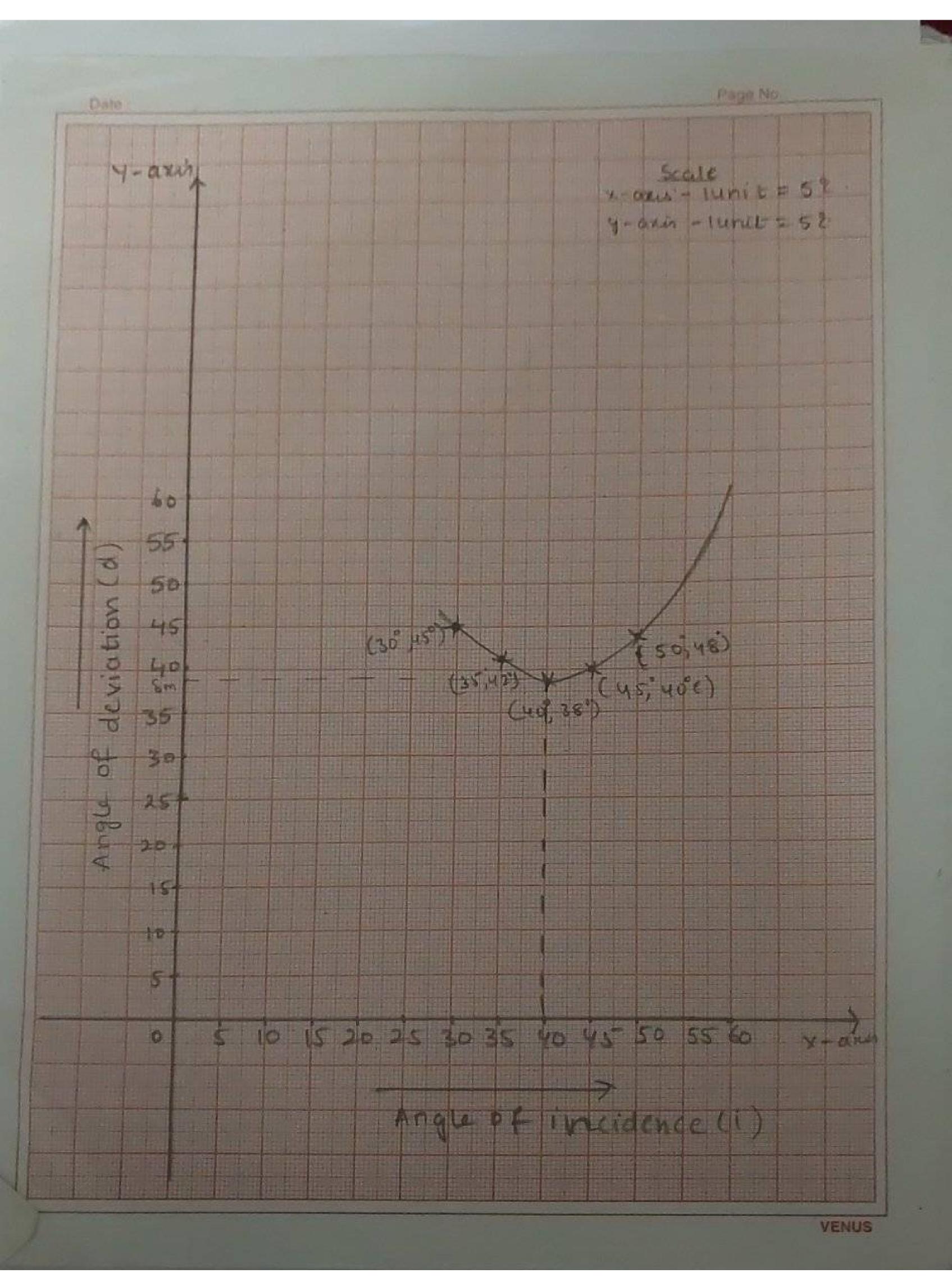
i-d curve: A graph is drawn with the angle of incidence on x-axis and the angle of deviation on y-axis. It is a curve as shown when i is gradually increased the angle of deviation when i is gradually increased the minimum and first decreases and reaches the minimum and the increases. The minimum angle is called angle of minimum deviation (D). The value of D' is obtained from i-d curve. The readings are tabulated as shown below. The Refractive index on the material of the prism can be obtained fromthe formula $\frac{1}{2} = \sin\left(\frac{A+Dm}{2}\right)$

the trace ABC of the principal Section of the prism is taken on a white paper fixed to a drawing board.

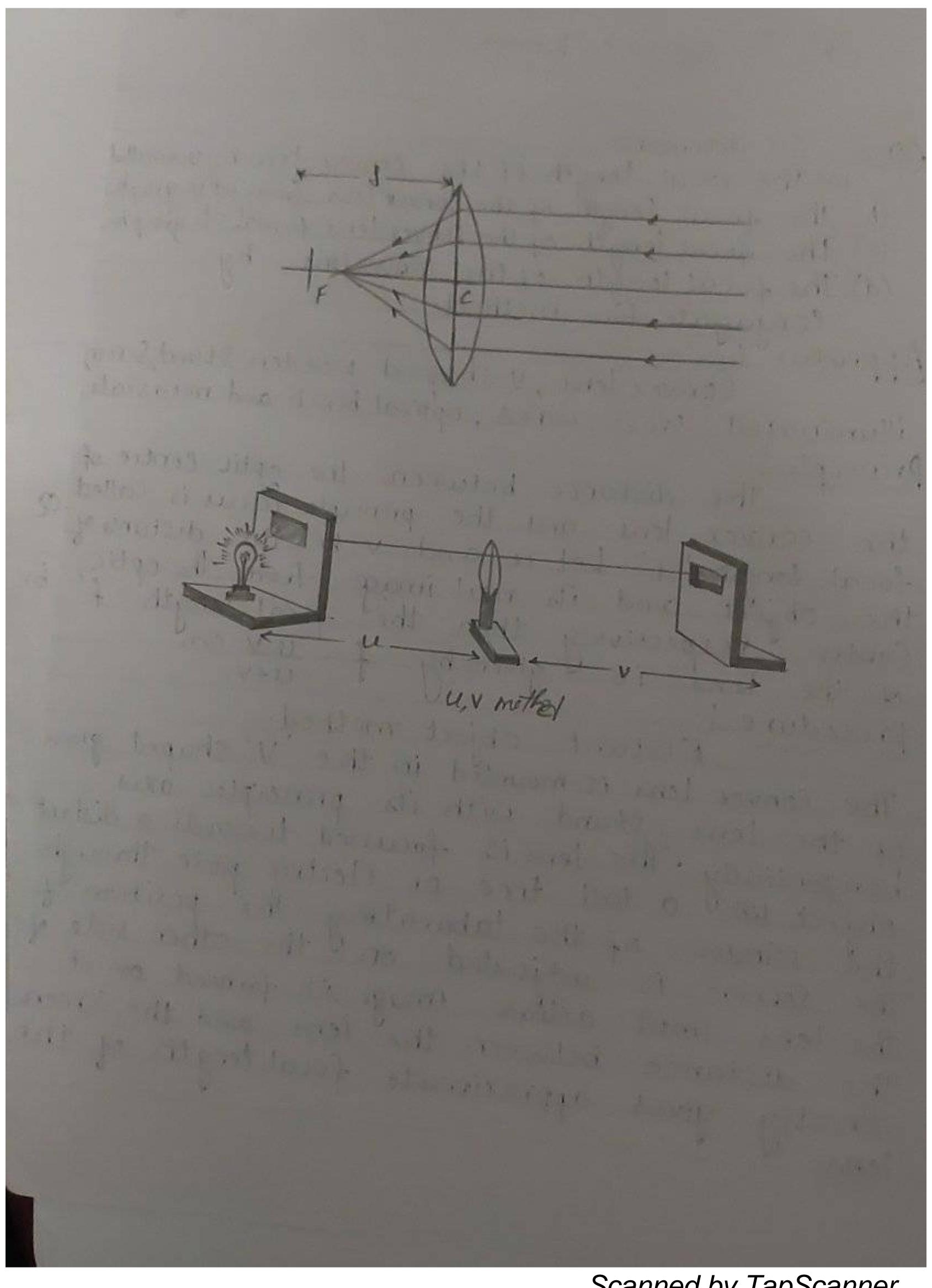
Two parallel line PA and TU are drawn one on either side of A Very close to it. Two point pins P and Q are pinned Vertically to the drawing board on one of these lines PQ. The reflected images are Seen through the face AB and two more pins R and S are pinned Vertically in line with the images. The lines RS gives the reflected ray corresponding to the incident ray PQ. Similarly the line VW that gives the reflected ray of TU is also traced the angle ROV blw the lines RS and VW at O' gives twice



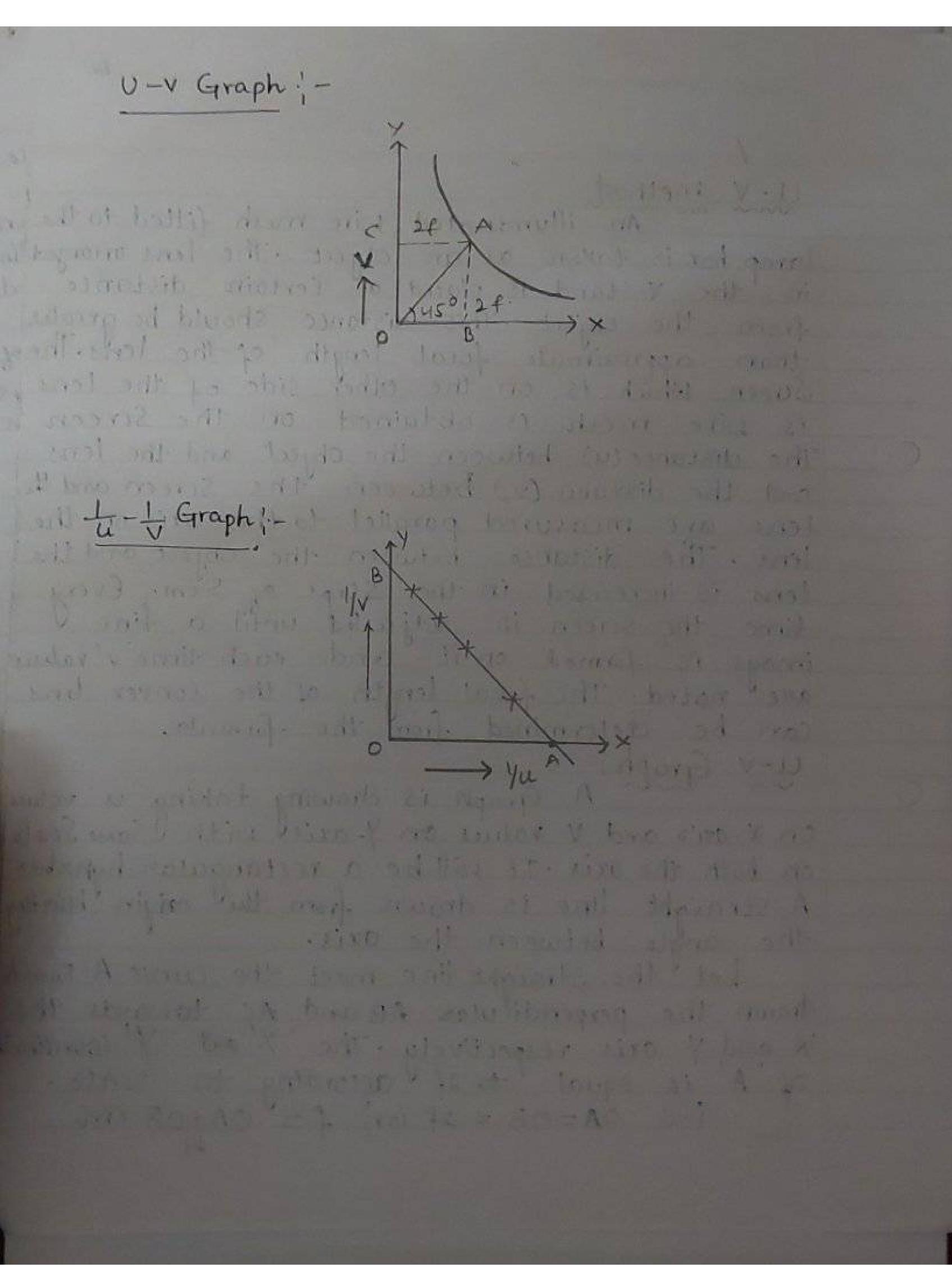
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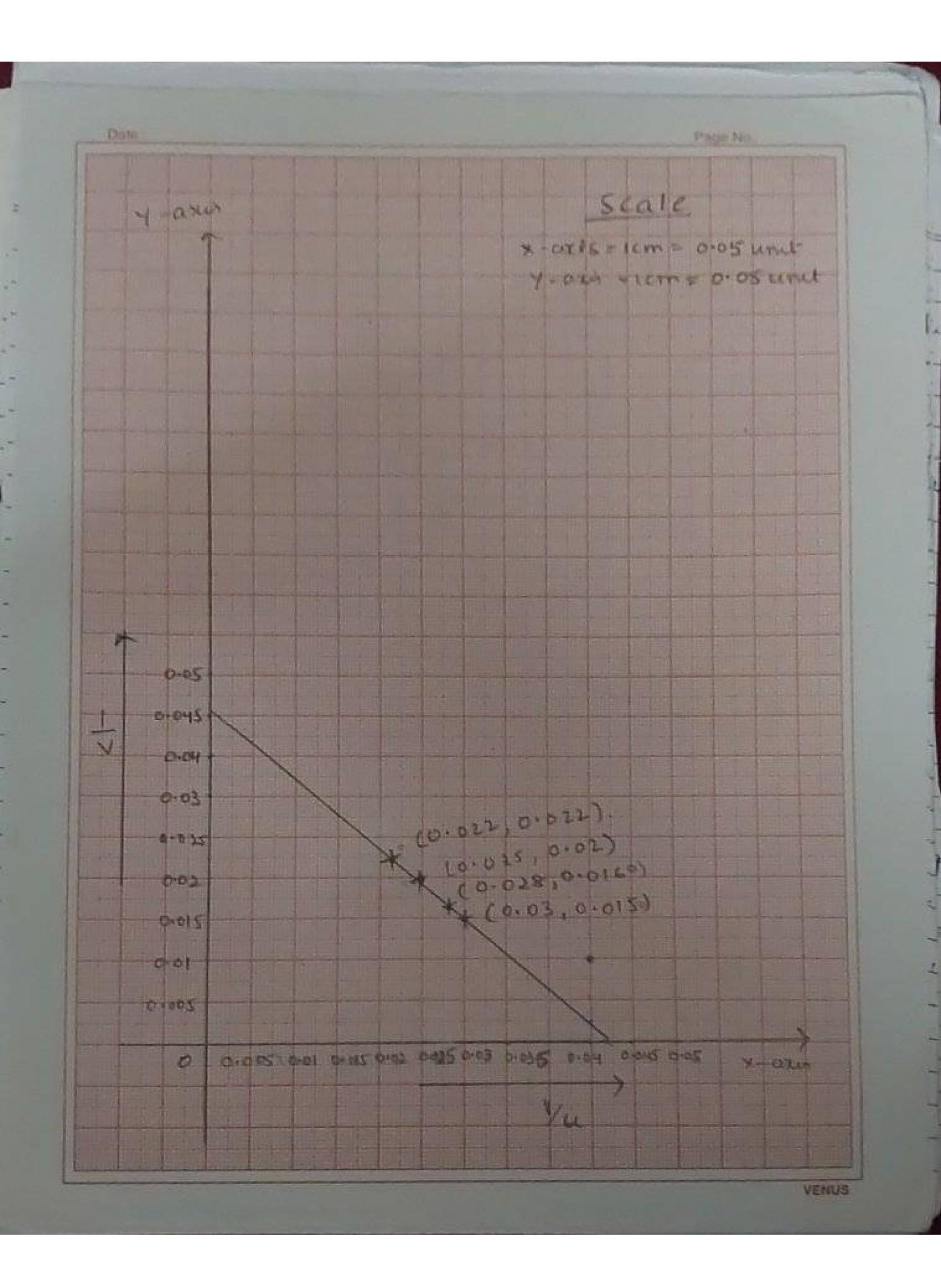


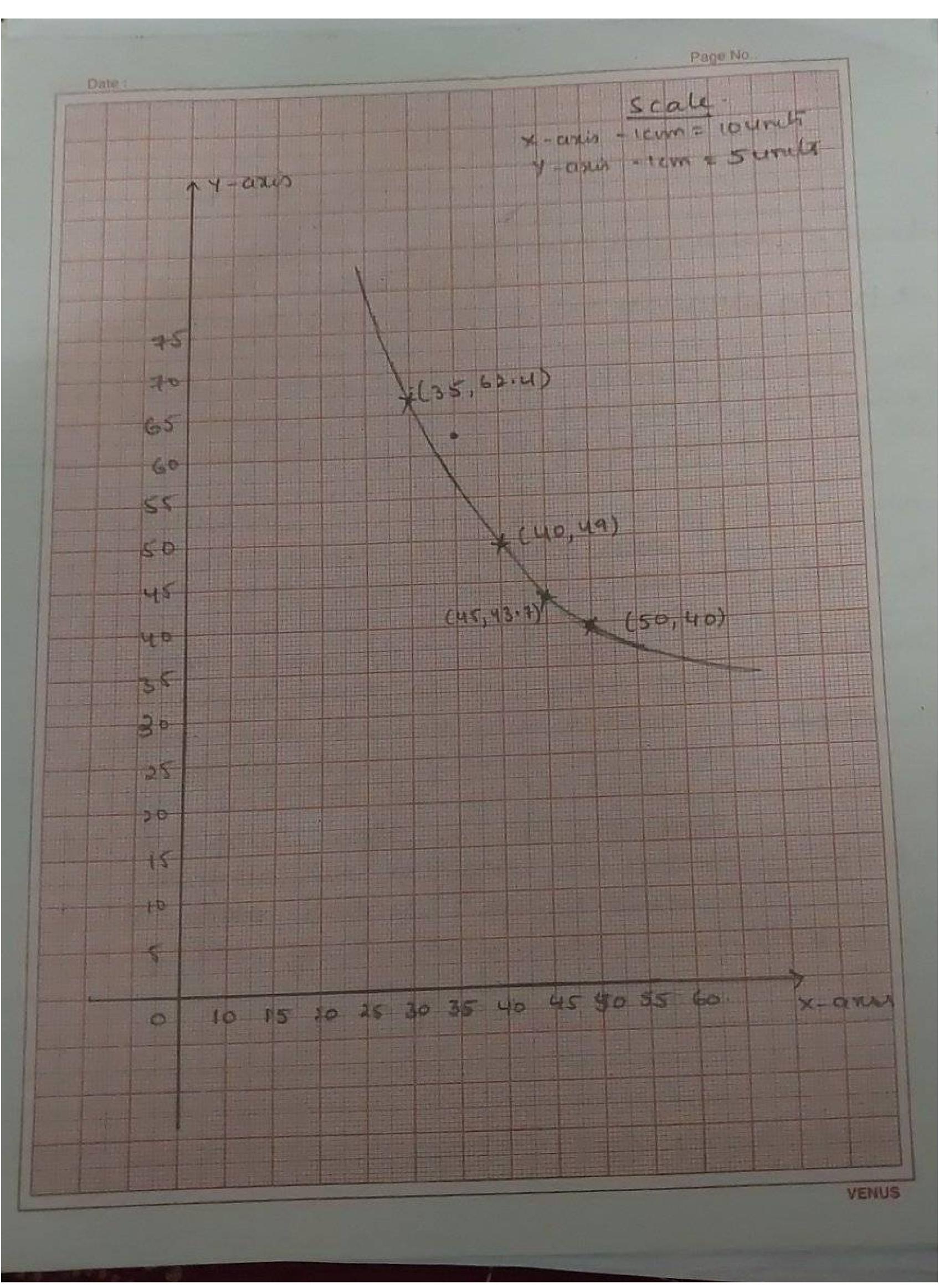
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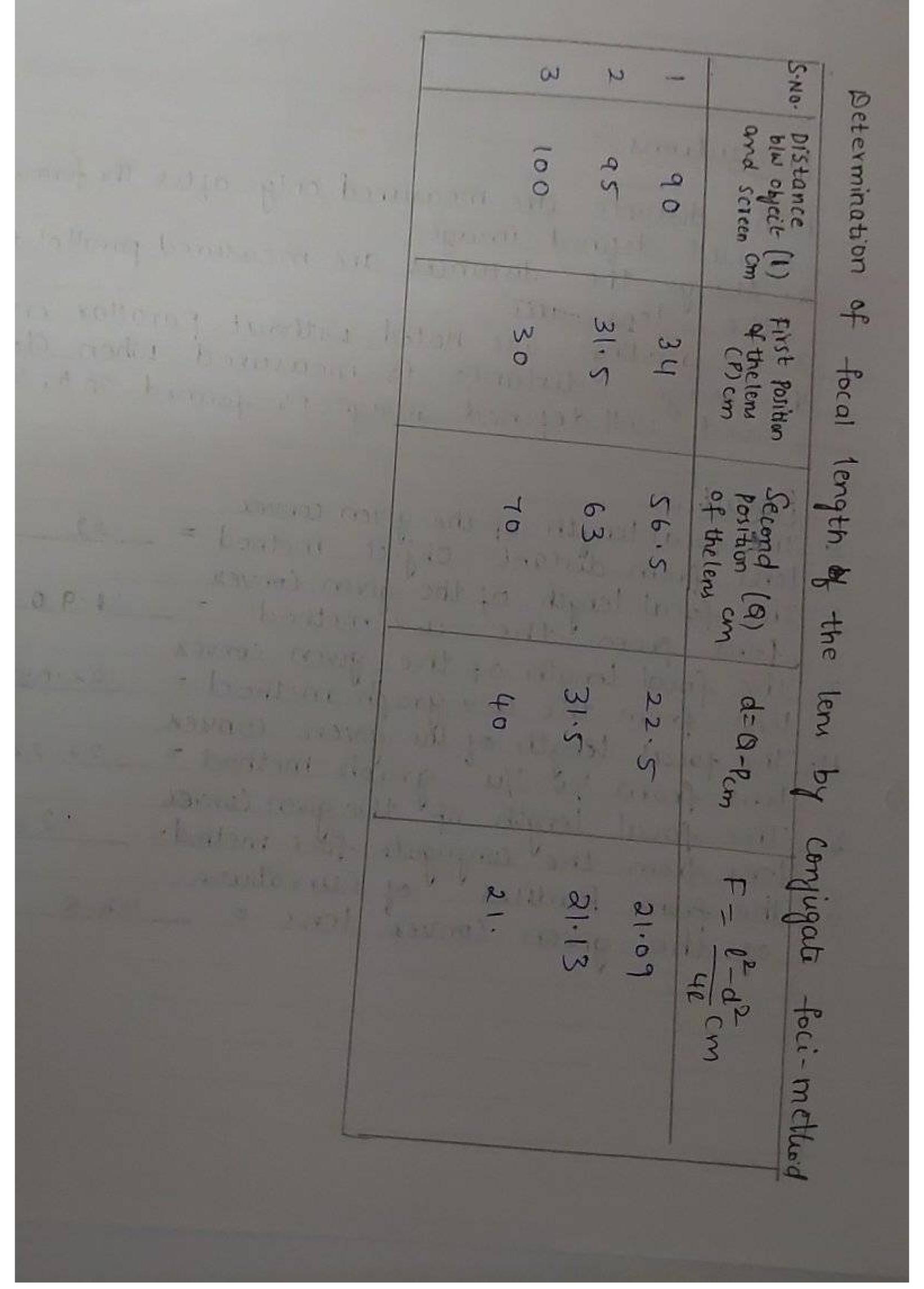


Date : Name of the Experiment: Page No : 7 ta-to Graph :and to values on y-axis with the Same scale on both the axis. It will be Straight line making intercepts of and OB on both axis as shown in the graph. Then f = 2 cm. Conjugate foci method for lens displacement method. The Object stand o and Screen sare placed on the optical bench seperated by a distante placed very close to the object and then slowly moved towards the screen. At a certain position a clear and magnified image forms on the screen. After nothing this position, the lens again slowly moved towards the screen other position (or) a real diminished and inverted. image is obtained on the Screen, the positioner. Q of the lens is noted. The displacement of the lens el=Q-p for the two images isobtained. The experiment is repeated for different values of 1, everytime the displacement d' is noted land réadings are tabulated. Observation Focal length of alens in distant object welled is 21 cm APHIL

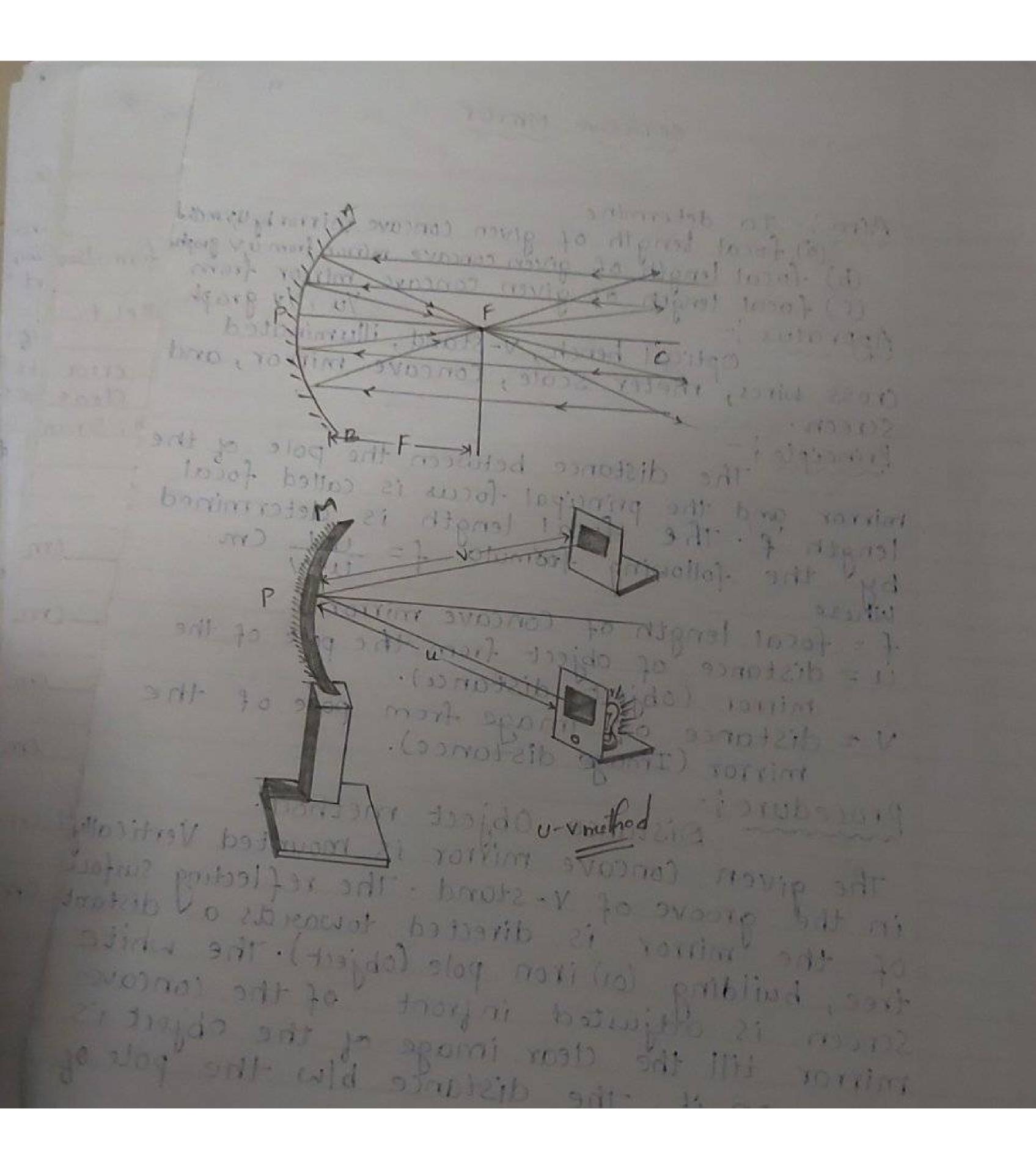
The the to	UN -5 W P - 1	S.N.P
focal length	300	object (m)
al length	0.02	Ch cm-
length 20.90 I the convex lens from Yesture of the conv	65.3 69.4 69.4	Timoge (im)
Con lens	0.02 8	V Cm
his 21.9	29.07.48 22.022	4- W-2 G3
12 2 2 1 2 1 2 2 1 2 2 1 2 2 2 2 2 2 2	4.0 m. 1.0 m. 1.	The second second







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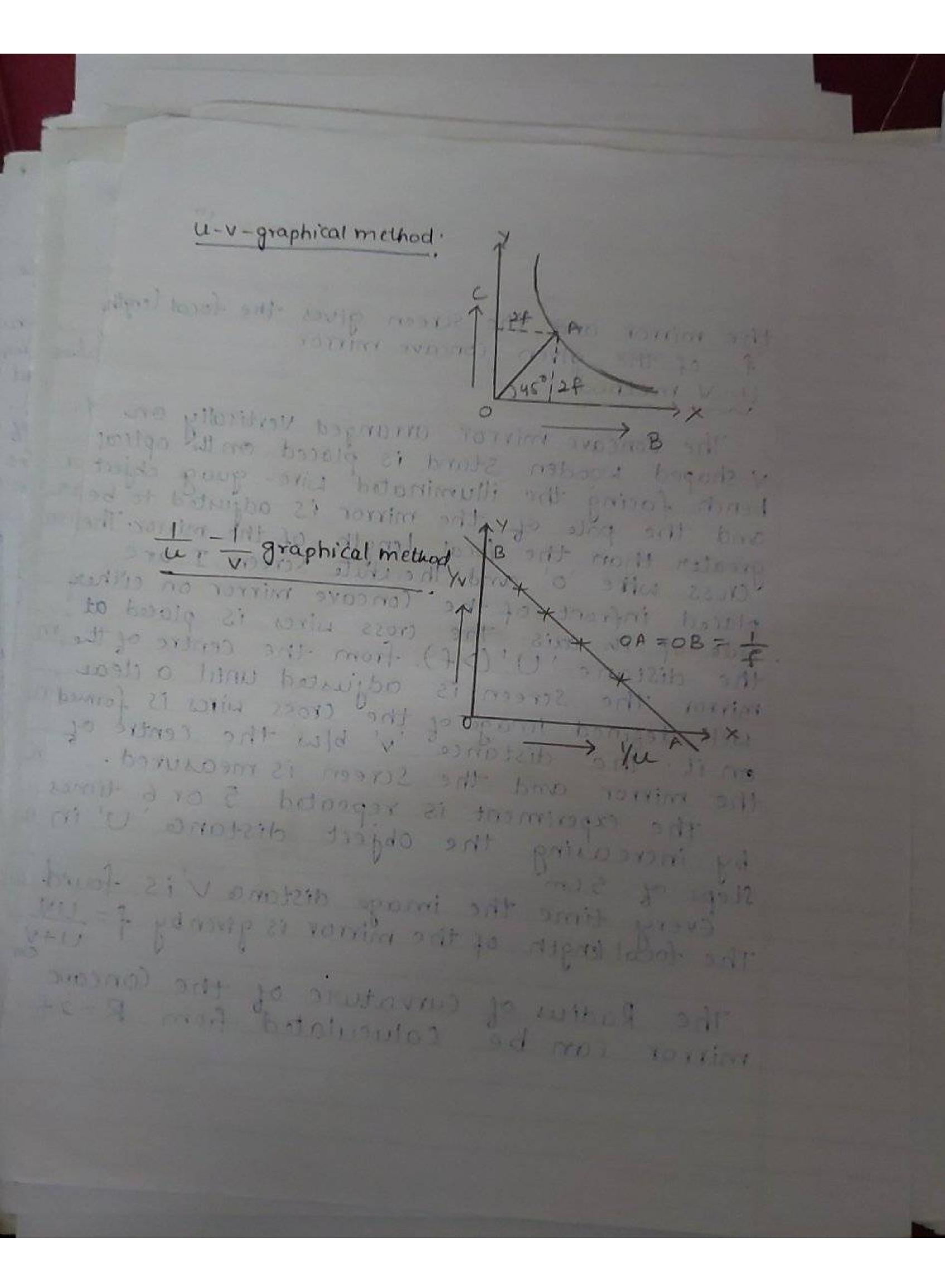


the mirror and the screen gives the focal length?

I' of the given concave mirror.

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The Concave mirror arranged Vertically on V-shaped wooden stand is placed on the optical bench facing the illuminated wire- guage object and the pole of the mirror is adjusted to be greater than the focal length of the mirror. The cross whee o' and the white screen I are placed infront of the Concave mirror on either side of its oxis. The cross wires is placed at the distance 'U'(>f) from the centre of the mirror. The screen is adjusted until a clear well defined image of the cross wires is formed on it. The distance v' blw the centre of the mirror and the screen is measured. the experiment is repeated 5 or 6 times by increasing the object distance U' in Every time the image distance Vis found.
The focal length of the mirror is given by f = UV The Radius of curvature of the Concarc mirror can be caluculated from R=2f.



U-V graphical method

A graph is drawn taking I and I on X and y oxes with the Same Scale on both the axes. It will be a straight line making intercepts. OA and OB on both the axes as shown in the diagram

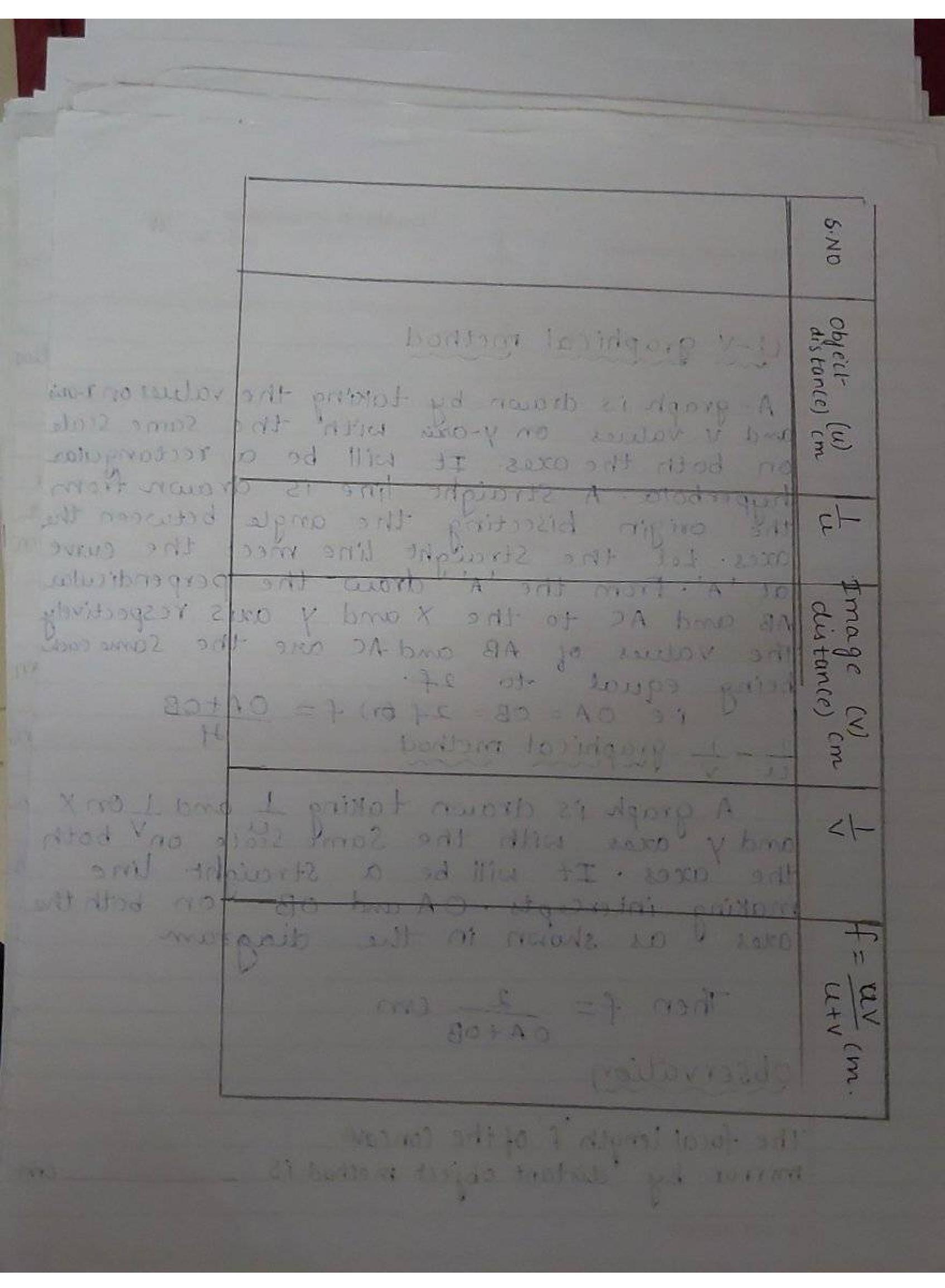
Then f = 2 cm

Observation

The focal length f of the concave mirror by distant object method is

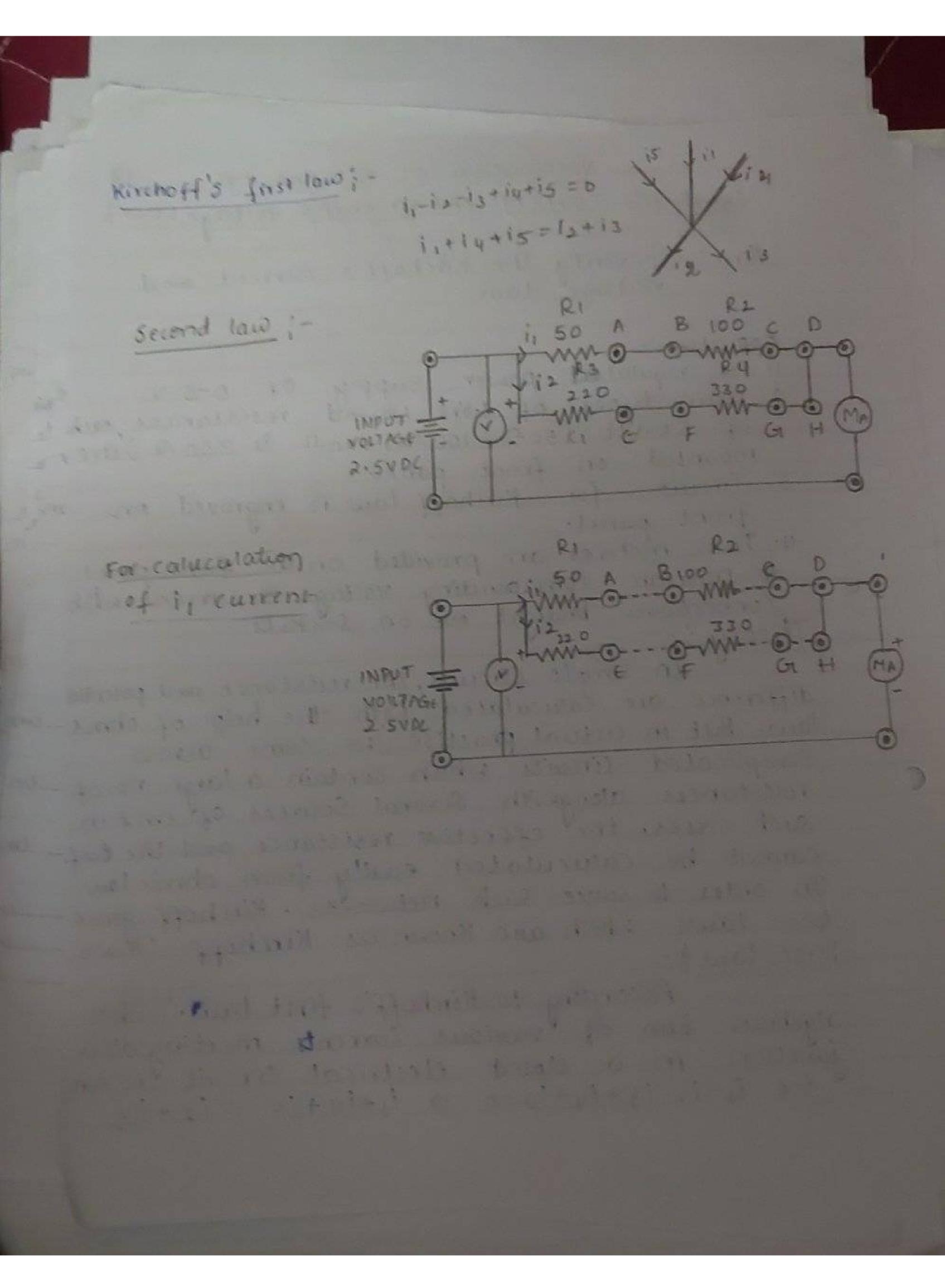
cm

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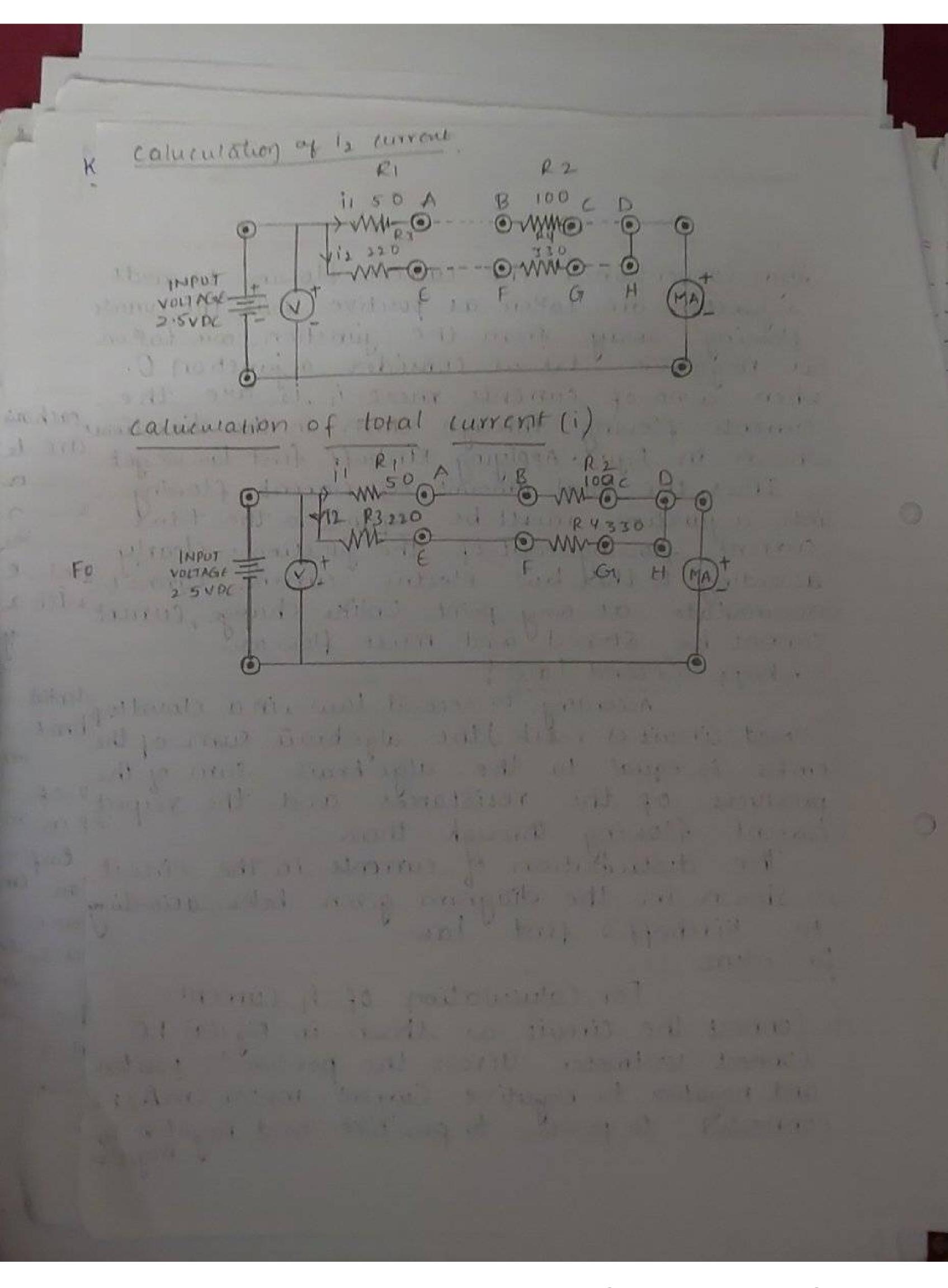


Meste 1	Name of the Experiment:	
	Precautions !-	
	1. The Centres of cross-wires, the mirror the Si height and the Centre of the Screen Sho lie at Should be at the Same height a the table.	uld
	2. The distances are measured from the pole the mirror, parallel to its axis 3. The image distances is measured when a image is formed on the Screen. 1. The distances are measured without	
	parallax error.	
	The focal length of given concave mirror - from object distant method =	
	The -focal length of given Concave mirror from u-v method =	0
1	The focal length of given concave mirror from U-vgraph method =	(
14.7	The focal length of given concave mirror from 1/4 and 1/4 graph method=	(
5. Th	he Radius of Curvature of given Concave mirror=	
AP III	T. NUZUID	

(Kirchoff's Current and Kircohff's voltage Law). Aim: - To verify the Kirchoff's current and voltage law. DC regulations power supply of 0-5 V. 2. Four types of blire bound resistances, each by of 5 Natt (502, 1001, 2201 & 330-2) are 1; mounted on front panel. 3. Circuit for Kirchoff law is engraved on 4. Two meteres are provided on the front panel e to measure Corresponding Voltage & current with Connections brought out on sockets Theory : In simple circuits, the resistance and potential difference are caluculated with the help of ohms law. But in actual practise, we come across complicated circuits which contain a large no of resistances alongwith Several Sources of emfin such cases, the effective resistance and the long cannot be caluculated easily from ohm's law: In order to solve such networks. Kirchoff gave two laws which are Known as Kirchoff laws. According to Kirchoff's first law." The algebraic Sum of various Currents meeting at a junction in a closed electrical Circuit is zoro i.e ii-i2-i3+i4+i5=0 \(\frac{1}{2}\) ij+i4+i5 = i2+i3.



Sign Convention i The current flowing towards = a junction are taken as positive while the currents flowing away from the junction are takenas negative. Let us consider a junction 0. when a no of currents meet i, is are the e currents flowing through them in the directions Shown in Figur. Applying Kirchoff first law we get Thus the total amount of current flowing by into a junction must be equal to the total current flowing out of the junction. clearly according to they law electric current commot accumulate at any point. Unlike change, current; cannot be Stored and must flow on? Kirchoff Second law! According to second law in a closed loop (closed circuit or much) the algebraic sum of the emps is equal to the algebraic sum of the products of the resistances and the respect current flowing through them. The distrubution of currents in the circuit is shown in the diagram given below according to Kirchoff's first law. Procedure : For Caluculation of it current. 1. Connect the circuit as shown in Fig 1(a) i.e. Connect voltmeter across the positive to positive and negative to negative Current meter (mA) is Connected to positive to positive and negative to



5-NO	Applied (v)	20-2	100 SL	I lexp	IIth = V RITE	7. of = I exp-Ith X to
			Digger.	Curry	$(mA) = \frac{V}{RS_i}$	(~cxp+1(m)
y reds	10000	to the same			W. The state of th	
1	ANTENNA BE	Lymber	521 6 7.			
A) 10 and	3		2	20	20	
1 22	4	1:3	2.6	26	26.6	2.281.
	5	1.6	3.3	34	3.33	2.081.
For	curren E					
8-110	Applied voltage(v)		V4.	I2exp	I21h = 12+R4 (mA) = V RSZ	7-cb = 12exp-Ithe) difference (Icxp+Ithe)
		J. Charles			IN THE REAL PROPERTY.	
		S1210		30 30		
	3 .	1-2	1.8	5	5.45	7.69.1.
	4	1.5	2.3	7	7. 23	3-23-1
1000		The second second	2 1	5	9.09	0.991
	5.	2	2-9	9	4.09	
	5	2			7.09	
	5	2				

Page Na . 16 Name of the Experiment : Date: = V/2R Amp is =? Amp (convert to milliamp) (ix1000 = m A) Caluculation of total current. Connect the circuit as Shown in fig 1(0) it connects, Voltmeter point A and B or Cand D or E and E; or Gand H' Also connerest current meter (mA) and voltmetere positive to positive and negative to negative Total current = i+12 Convert the milliampere (ix 1000 = mA) Formula ! V-IR1-IR2=0 RI+R2 R3+RY RS2 RS1+RS2) Resultic 7, of difference in I exp and I the is about to 1. hence Kirchoff laws are Verified. AP HIT.

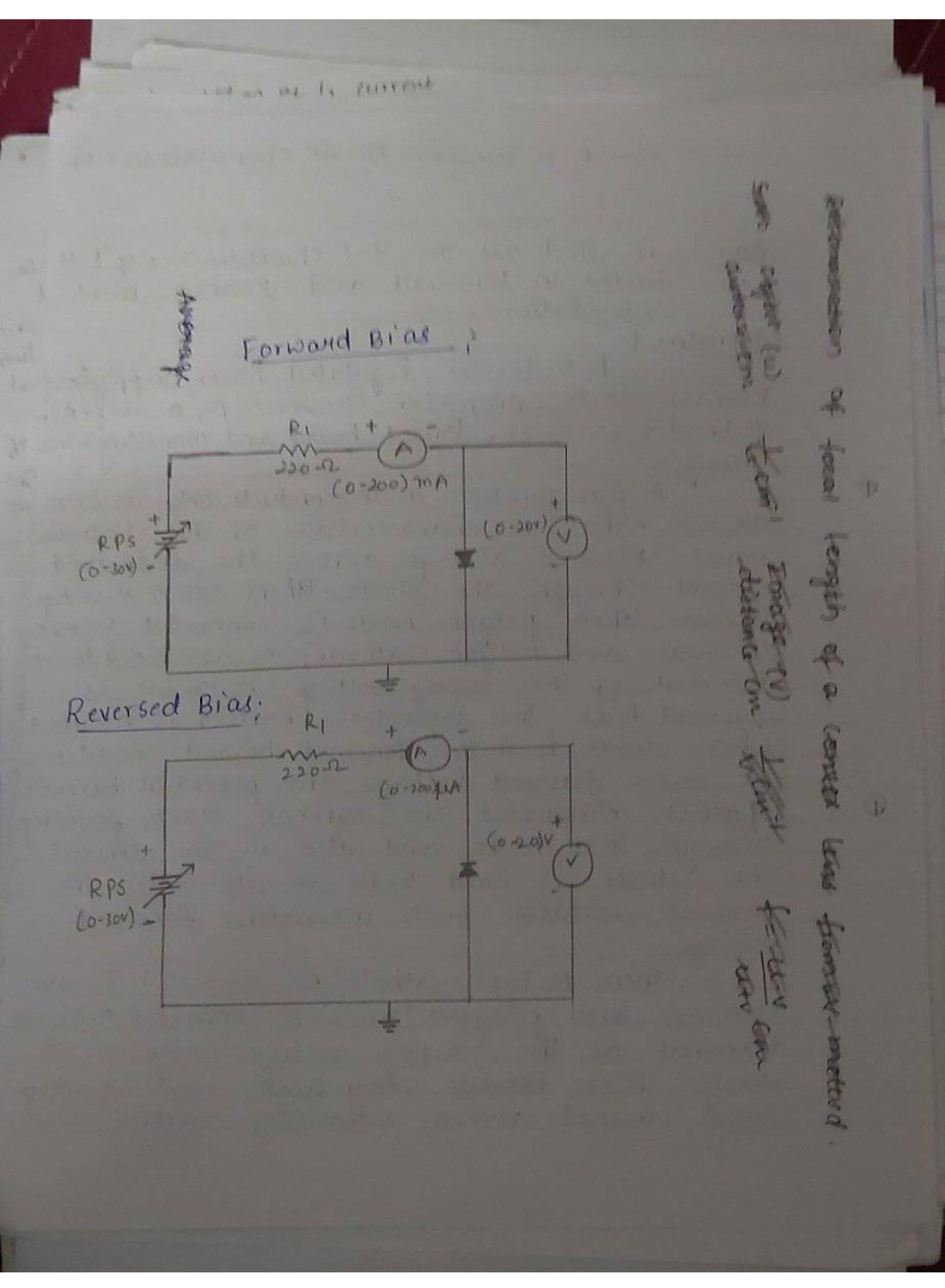
010	Applied voltagelv)	100	Tthe V(Rs19) RS1		7-9 clifferen =	(Iexp-Itne) XII	0.
		1 1 1 1 P S		9	The state of the s		
	2.5		- 3 (120+220) = 5.2×(120+220)	29.6	125.4-25) (25.4+25) (25.4+25) \$29.6 - 29)	X100 = 1.58;	10
				1 5	(29.5+29)	x 100 = 2.04.	
							ļ

Aim !- To find out the V-I characteristics of P-N diodes in Forward and Reverse bias configurations.

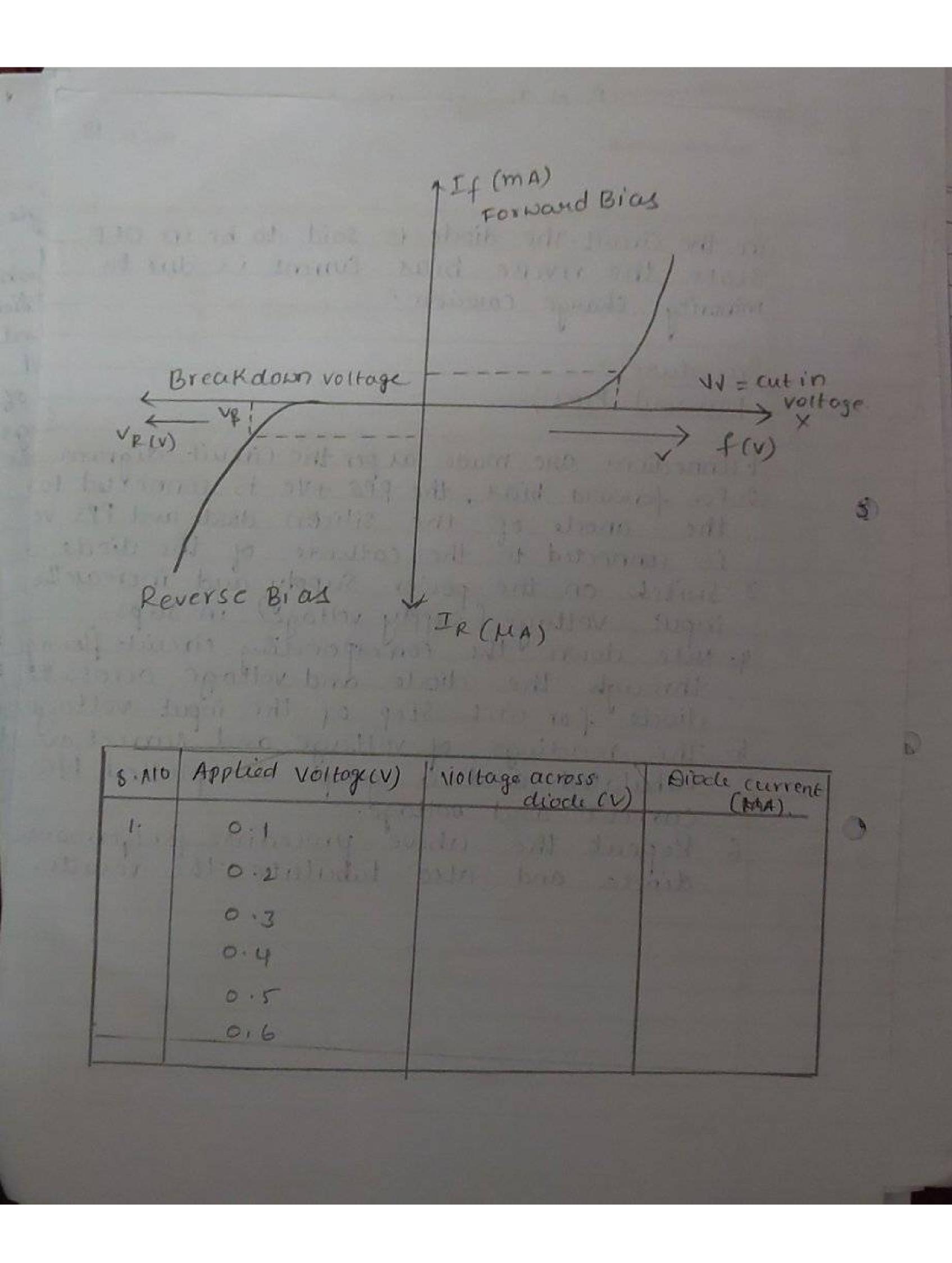
Resistor 1KSL, Ammeter (0-200 mA, 0-200 fith), Voltmeter (0-20V), Bread board and connecting wires

direction. The V-1 characteristics of the diade are curve between voltage across the diode and Current through the diode . When external voltage When p-type (anode is connected to the 15 Zero. and n-type (cathode) is connected to -ve terminal terminal of the supply voltage is known as forward bias. The potential barrier When diode is in the forward biased condition At some forward voltage the potential barrier. torgother eliminated and current starts flowing through the diods and also in the circuit. diode is Said to be in ON state. The current increases with increasing forward voltage.

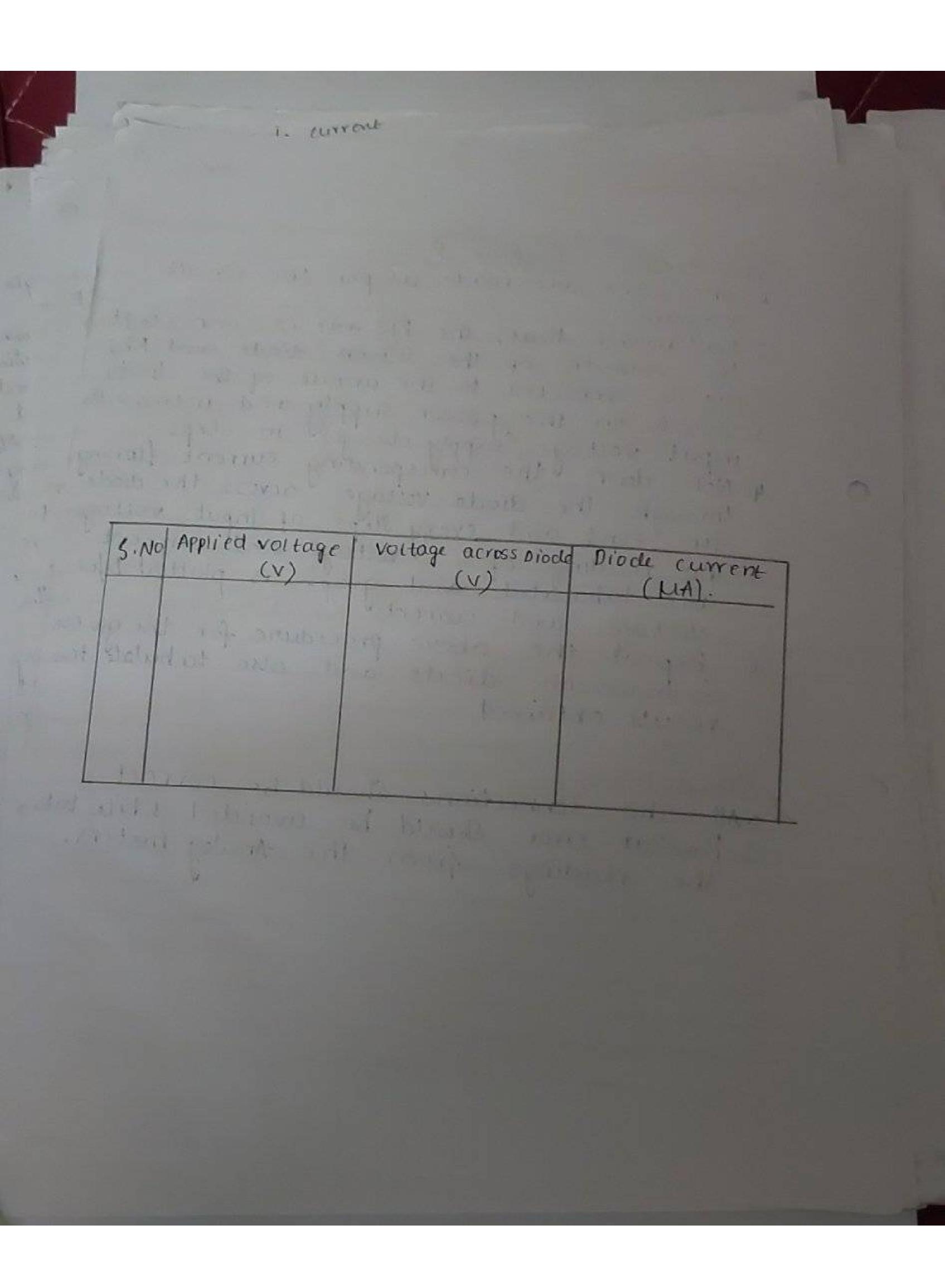
terminal and p-types (Anode) is connected to the -ve terminal of the supply voltage is known as reverse bias becomes very high and a very Small current (reverse saturation current) flows

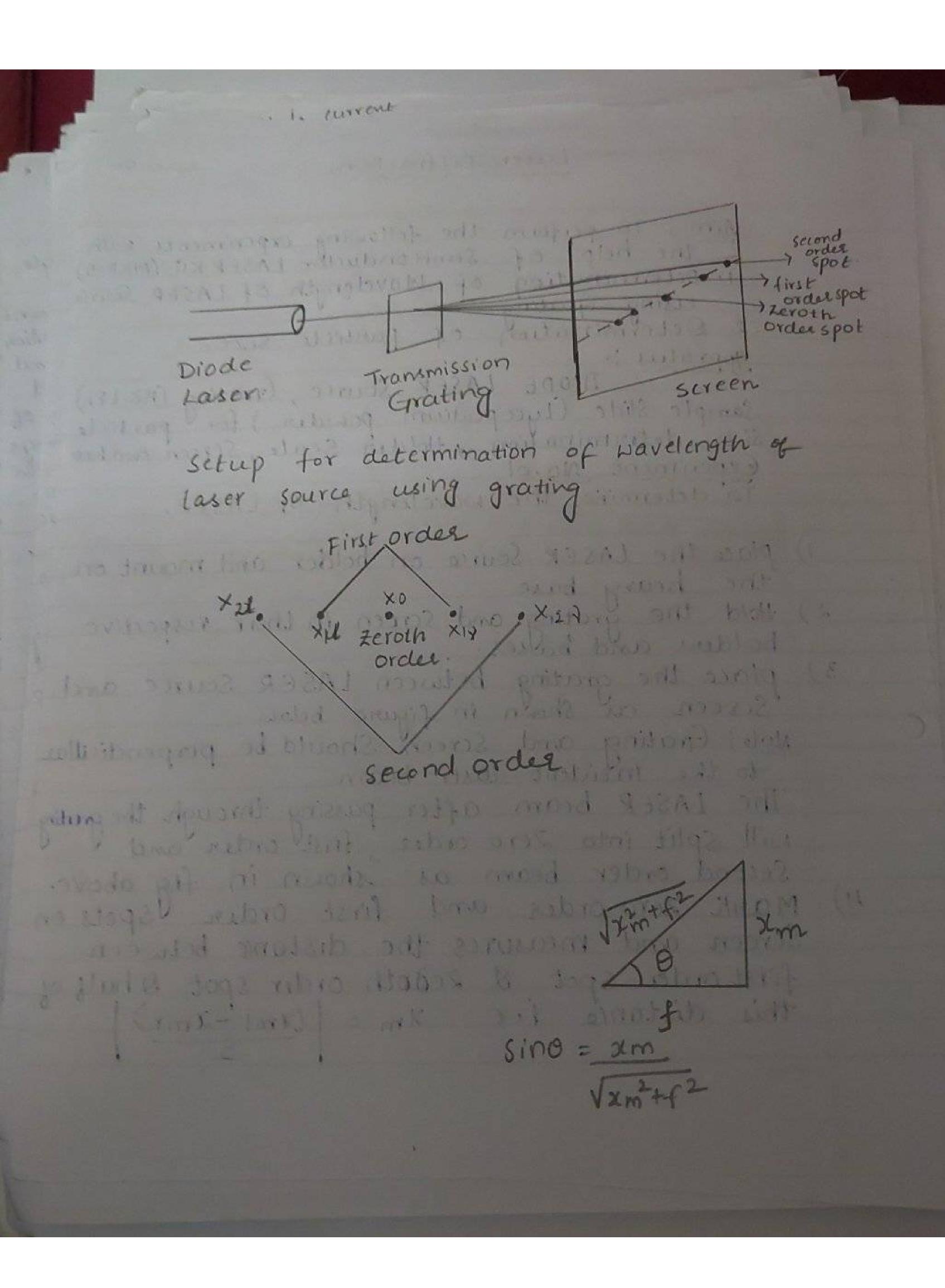


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Page No: 19 Name of the Experiment: Date : - Reverse Bias 1. connections are made as per the circuit 2. For reverse bias, the RPS tre is the cathode of the silicon diode and RPS -Ve is connected to the anade of the diode 3. Switch on the power supply and increase the input voltage (supply change) in Steps. 4. Note down the consesponding current flowing through the diode voitage across the diode for leach and every steps of input voltage voltage and current graph is plotted b/w 5. The reading of 6. Repeat the above procedure for the given Germanium diade and also tabulate the result obtained the Connections Should be correct. Precautions 2. Parallax error should be avoided while taking the readings from the Analog meters. APHIT.





Page No : 21 Name of the Experiment: Date : put sin om in formula as below my - dsinom dam m /22m+ FZ Where m = order of spots 1 = Wavelength of LASER beam (nm)
d = Resolution of grafting (=1/grating of element)

2m = Distance between Zero order spot & 2 = Distance blw screening & grating elementers NOTE if wavelength of Source is known Similarly using relation (1), grating element (an be calutulated. AP HIT.

Caluculations. Grating = 100: f=25 cm =25 x16 cm $Am = \frac{dam}{m\sqrt{am^2 + \rho^2}}$ m=1 > A = 10×10-6 × \$7×10-2 1× V (1.7×102)2+(25×10-2)2 = 0.678 x 10 6 m = 0.678 x 10 m A = 678 nm m=2 $\lambda = 10 \times 10^6 \times 3.5 \times 10^2$ $\frac{2 \times \sqrt{(3.5 \times 10^{7})^{2} + (25 \times 10^{7})^{2}}}{= 0.693 \times 10^{6} \text{m}}$ $= 693 \times 10^{6} \text{m}$ = 693 nmGrating & 300 $f = 19.5 \text{ cm} = 19.5 \times 10^{-2} \text{ cm}$; $\lambda = dxm$ $d = \frac{1}{300} \text{ mm} = \frac{1}{300} \times 10^{3} \text{m} = 3.33 \times 10^{6} \text{m}.$ for m=1. = 3.33 x 10 6 x 4 x 10 1 X \ (4x10-2)2+ (19.5x102)2 = 0.6698 x10-6 = 670 × 10-9m = 670 nm. for m=2; $\lambda = 3.38 \times 10^{-6} \times 8.5 \times 10^{-2}$ ·2×√(8·5×10-2)2+(19.5×10-2)2. = 0.666 X 10-6 = 666 × 10-9 = 666 nm

